

Complementary power Darlington transistors

Features

- Monolithic Darlington configuration
- Integrated antiparallel collector-emitter diode

Application

■ Linear and switching industrial equipment

Description

The devices are manufactured in planar technology with "base island" layout and monolithic Darlington configuration. The resulting transistors show exceptional high gain performance coupled with very low saturation voltage.

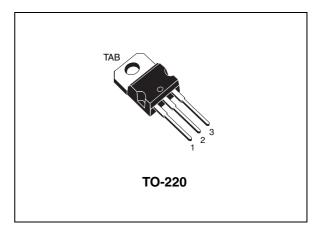


Figure 1. Internal schematic diagrams

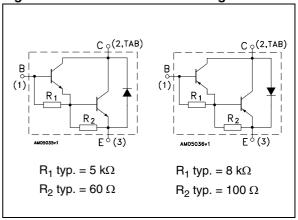


Table 1. Device summary

| Part number | Marking | Polarity | Package | Packaging |
|-------------|---------|----------|---------|-----------|
| TIP142T | TIP142T | NPN | TO-220 | Tube |
| TIP147T | TIP147T | PNP | 10-220 | Tube |

1 Absolute maximum ratings

Table 2. Absolute maximum ratings

| Symbol | Parameter | Value | Unit |
|------------------|--|------------|------|
| V _{CBO} | Collector-base voltage (I _E = 0) | 100 | V |
| V _{CEO} | Collector-emitter voltage (I _B = 0) | 100 | V |
| V _{EBO} | Emitter-base voltage (I _C = 0) | 5 | V |
| Ic | Collector current | 10 | Α |
| I _{CM} | Collector peak current | 20 | А |
| I _B | Base current | 0.5 | Α |
| P _{TOT} | Total dissipation at T _{case} = 25 °C | 90 | W |
| T _{STG} | Storage temperature | -65 to 150 | °C |
| TJ | Max. operating junction temperature | 150 | °C |

Note: For PNP type voltage and current are negative.

Table 3. Thermal data

| Symbol | Parameter | | Unit |
|-------------------|--------------------------------------|-----|------|
| R _{thJC} | Thermal resistance junction-case max | 1.4 | °C/W |

2 Electrical characteristics

 T_{case} = 25 °C; unless otherwise specified.

Table 4. Electrical characteristics

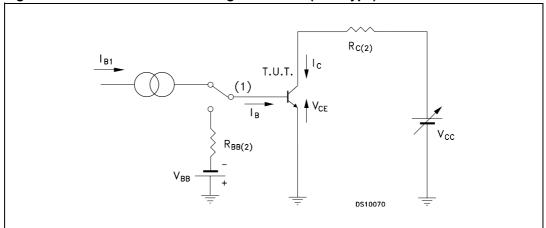
| Symbol | Parameter | Test conditions | | Тур. | Max. | Unit |
|--------------------------------------|---|---|-----|------|------|--------|
| I _{CBO} | Collector cut-off current (I _E = 0) | V _{CB} = 100 V | | | 1 | mA |
| I _{CEO} | Collector cut-off current (I _B = 0) | V _{CE} = 50 V | | | 2 | mA |
| I _{EBO} | Emitter cut-off current (I _C = 0) | V _{EB} = 5 V | | | 2 | mA |
| V _{CEO(sus)} ⁽¹⁾ | Collector-emitter sustaining voltage (I _B = 0) | I _C = 30 mA | 100 | | | V |
| V _{CE(sat)} ⁽¹⁾ | Collector-emitter saturation voltage | $I_C = 5 A$ $I_B = 10$ $I_C = 10 A$ $I_B = 40$ | | | 2 3 | V V |
| V _{BE(on)} ⁽¹⁾ | Base-emitter on voltage | I _C = 10 A V _{CE} = | 4 V | | 3 | V |
| h _{FE} ⁽¹⁾ | DC current gain | $I_C = 5 A$ $V_{CE} =$ $I_C = 10 A$ $V_{CE} =$ | | 1 | | |
| | Resistive load | | | | | |
| t _{on} | Turn-on time | $I_C = 10 \text{ A}$ $R_L = 3$ | 3 Ω | 0.9 | | μs |
| t _{off} | Turn-off time | $I_{B1} = -I_{B2} = 40 \text{ mA}$ | | 4 | | μs |

^{1.} Pulse test: pulse duration \leq 300 μ s, duty cycle \leq 2 %.

Note: For PNP type voltage and current are negative.

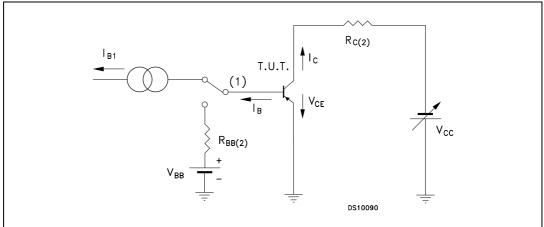
2.1 Test circuits

Figure 2. Resistive load switching test circuit (NPN type)



- 1. Fast electronic switch
- 2. Non-inductive resistor

Figure 3. Resistive load switching test circuit (PNP type)



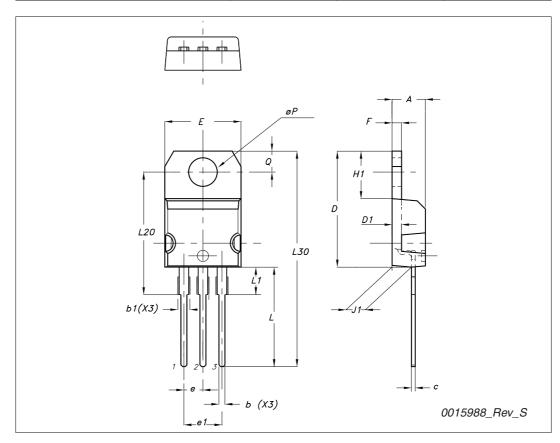
- 1. Fast electronic switch
- 2. Non-inductive resistor

3 Package mechanical data

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TO-220 type A mechanical data

| Dim | mm | | | |
|-----|-------|-------|-------|--|
| Dim | Min | Тур | Max | |
| A | 4.40 | | 4.60 | |
| b | 0.61 | | 0.88 | |
| b1 | 1.14 | | 1.70 | |
| С | 0.48 | | 0.70 | |
| D | 15.25 | | 15.75 | |
| D1 | | 1.27 | | |
| Е | 10 | | 10.40 | |
| е | 2.40 | | 2.70 | |
| e1 | 4.95 | | 5.15 | |
| F | 1.23 | | 1.32 | |
| H1 | 6.20 | | 6.60 | |
| J1 | 2.40 | | 2.72 | |
| L | 13 | | 14 | |
| L1 | 3.50 | | 3.93 | |
| L20 | | 16.40 | | |
| L30 | | 28.90 | | |
| ØP | 3.75 | | 3.85 | |
| Q | 2.65 | | 2.95 | |



TIP142T, TIP147T Revision history

4 Revision history

Table 5. Document revision history

| Date | Revision | Changes |
|-------------|----------|--|
| 21-Jun-2004 | 4 | |
| 20-May-2010 | 5 | Technology change from epitaxial base to planar base island. |

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